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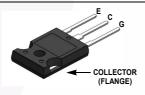
November 2013



SEMICONDUCTOR FGH50T65UPD 650 V, 50 A Field Stop Trench IGBT

Features

- Maximum Junction Temperature : T_J = 175^oC
- Positive Temperaure Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 1.65 V(Typ.) @ I_C = 50 A ٠
- 100% of Parts Tested ILM(2) •
- High Input Impedance •
- **Tightened Parameter Distribution**
- **RoHS** Compliant
- Short Circuit Ruggedness > 5 us @25°C

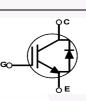


General Description

Using innovative field stop trench IGBT technology, Fairchild's new series of field-stop trench IGBTs offer optimum performance for solar inverter, UPS, welder, and digital power generator where low conduction and switching losses are essential.

Applications

- Solar Inverter, UPS, Welder, Digital Power Generator
- · Telecom, ESS



Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		650	V
V _{GES}	Gate to Emitter Voltage		±20	V
	Transient Gate to Emitter Voltage		±25	V
I _C	Collector Current	@ T _C = 25°C	100	А
	Collector Current	@ T _C = 100 ^o C	50	А
I _{CM (1)}	Pulsed Collector Current		150	А
I _{LM (2)}	Clamped Inductive Load Current	@ T _C = 25°C	150	A
IF	Diode Forward Current	@ T _C = 25°C	60	А
	Diode Forward Current	@ T _C = 100 ^o C	30	А
I _{FM(1)}	Pulsed Diode Maximum Forward Current		150	А
PD	Maximum Power Dissipation	@ T _C = 25°C	340	W
	Maximum Power Dissipation	@ T _C = 100 ^o C	170	W
SCWT	Short Circuit Withstand Time	@ T _C = 25°C	5	us
TJ	Operating Junction Temperature		-55 to +175	°C
T _{stg}	Storage Temperature Range		-55 to +175	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 second	ls	300	°C

Notes: 1: Repetitive rating: Pulse width limited by max. junction temperature

2: Ic = 150 A, Vce = 400 V, Rg = 10 Ω

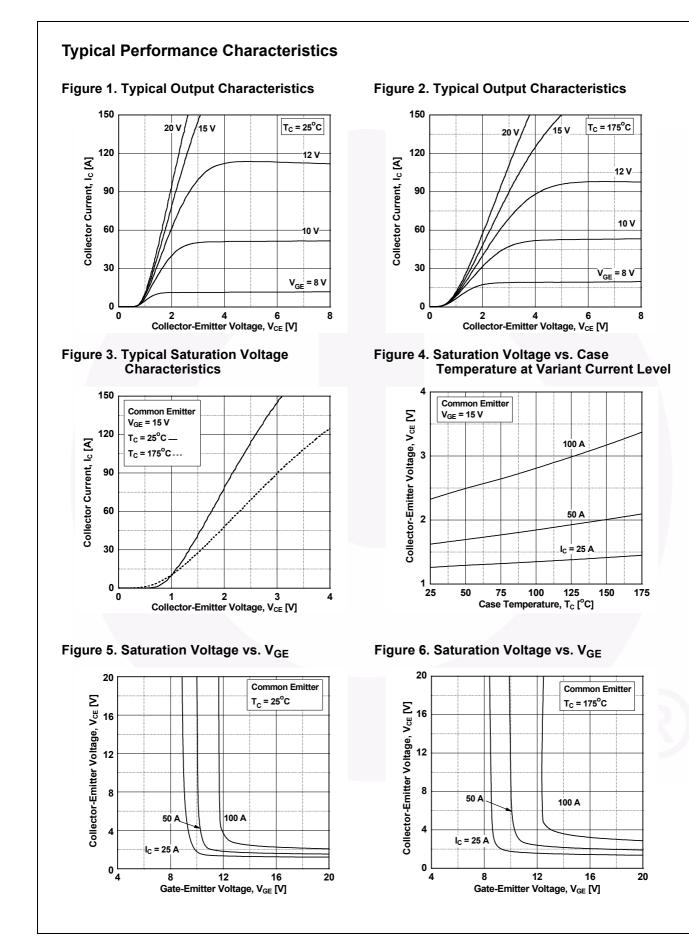
Thermal Characteristics

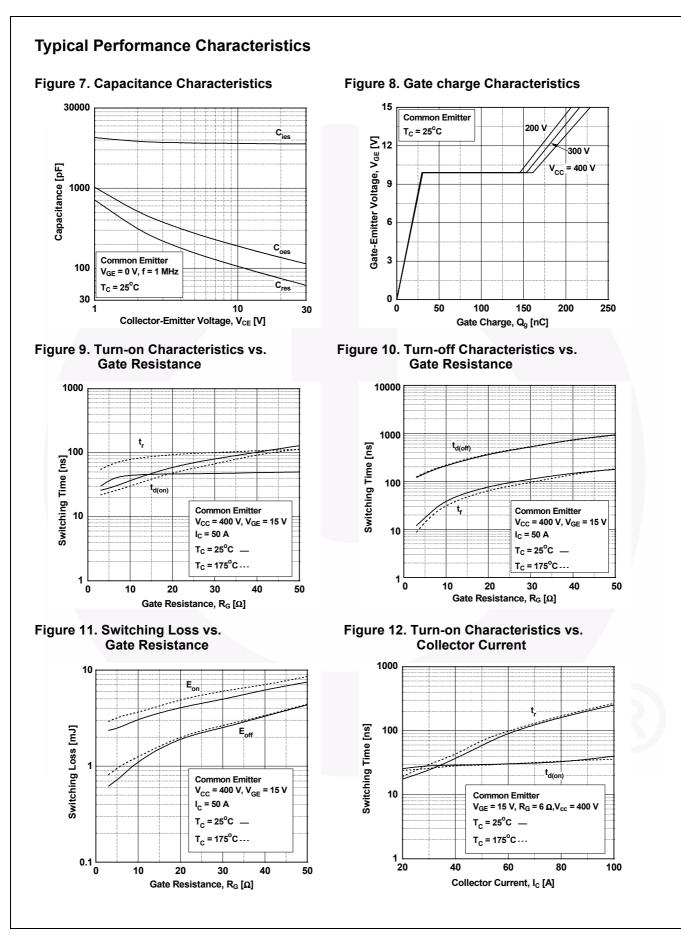
Symbol	Parameter	Тур.	Max.	Unit	
R _{θJC} (IGBT)	R _{0JC} (IGBT) Thermal Resistance, Junction to Case		0.44	°C/W	
$R_{\theta JC}(Diode)$	Diode) Thermal Resistance, Junction to Case		1.2	°C/W	
R _{0JA} Thermal Resistance, Junction to Ambient		-	40	°C/W	

Part Number FGH50T65UPD		Top Mark	Package	Packing Method	Reel Size	Tape Width		Quantity 30	
		FGH50T65UPD	TO-247 A03	Tube	N/A				
Electric	al Cha	racteristics of the		25°C unless otherwise not	ed				
Symbol Parameter			Test Conditions		Typ. Max		Unit		
Off Charac	teristics							·	
BV _{CES}		to Emitter Breakdown Volta	ige V _{GE} = 0 V,	$I_{\rm C} = 1 \rm{mA}$	650	-	-	V	
ΔBV_{CES} ΔT_J		ture Coefficient of Breakdov	wp.	I _C = 250 uA	-	0.65	-	V/ºC	
I _{CES}	Collector	Cut-Off Current	V _{CE} = V _{CES}	_s , v _{ge} = 0 v	-	-	250	μA	
I _{GES}	G-E Leak	age Current		_S , V _{CE} = 0 V	-	-	±400	nA	
On Charac	teristics							<u> </u>	
V _{GE(th)}	G-E Threshold Voltage		I _C = 50 mA	I _C = 50 mA, V _{CE} = V _{GE}		6.0	7.5	V	
		<u> </u>	I _C = 50 A, V		-	1.65	2.3	V	
V _{CE(sat)}	Collector	to Emitter Saturation Volta		/ _{GE} = 15 V,	-	2.1	-	v	
Dynamic C	haracteris	atics							
C _{ies}	Input Car				-	3540	4710	pF	
C _{oes}		apacitance		V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz		110	146	pF	
C _{res}	-	Transfer Capacitance	f = 1 MHz			60	90	pF	
	Chavaotor	inting					1		
Switching (Delay Time			-	32	41	ns	
t _r	Rise Tim			V _{CC} = 400 V, I _C = 50 A,		59	77	ns	
t _{d(off)}	Turn-Off	Delay Time	Vac = 400			160	208	ns	
t _f	Fall Time		R _G = 6.0 Ω	, V _{GE} = 15 V,	-	22	29	ns	
E _{on}	Turn-On	Switching Loss	Inductive L	oad, T _C = 25ºC	-	2.7	3.5	mJ	
E _{off}		Switching Loss		-		0.74	0.96	mJ	
E _{ts}	Total Swi	tching Loss				3.44	4.46	mJ	
t _{d(on)}	Turn-On	Delay Time			-	29	-	ns	
t _r	Rise Time	e			-	72	-	ns	
t _{d(off)}	Turn-Off	Delay Time	V _{CC} = 400	V, I _C = 50 A,	-	166	-	ns	
t _f	Fall Time		R _G = 6.0 Ω	$R_G = 6.0 \Omega$, $V_{GE} = 15 V$, Inductive Load, $T_C = 175^{\circ}C$		19	-	ns	
Eon	Turn-On	Switching Loss				3.5	-	mJ	
E _{off}	Turn-Off	Switching Loss				1.2	-	mJ	
E _{ts}	Total Swi	tching Loss				4.7	-	mJ	
T _{SC}	Short Cir	cuit Withstand Time	V _{GE} = 15 V R _G = 10 Ω	V_{GE} = 15 V, V_{CC} =400 V, R _G = 10 Ω		-	-	us	
Qg	Total Gat	e Charge			-	230	345	nC	
Q _{ge}	Gate to E	mitter Charge	$V_{CE} = 400$	V, I _C = 50 A,	-	31	47	nC	
Q _{gc}	Gate to C	Collector Charge	VGE = 15 V	V _{GE} = 15 V		130	195	nC	

Electrical Characteristics of the Dioue T _c = 25°C unless otherwise noted							
Symbol	Parameter	Test Conditions		Min.	Тур.	Мах	Unit
V _{FM} Diode Forward Voltag	Diode Forward Voltage	$I_{\rm F} = 30 \rm{A}$	T _C = 25°C	-	2.1	2.7	V
	2.040 Formara Formage		T _C = 175 ^o C	-	1.78	-	
E _{rec}	Reverse Recovery Energy		T _C = 175 ^o C	-	46	-	uJ
t _{rr}	Diode Reverse Recovery Time	Reverse Recovery Time $I_F = 30 \text{ A}, \text{ di}_F/\text{dt} = 200 \text{ A/}\mu\text{s}$ $\frac{T_C = 25^{\circ}\text{C}}{T_C = 175^{\circ}\text{C}} - \frac{41}{144} - \frac{53}{144}$	53	ns			
41			T _C = 175 ^o C	-	144	-	
Q _{rr}	Diode Reverse Recovery Charge	76	106	nC			
~ "			T _C = 175 ^o C	-	486	-	

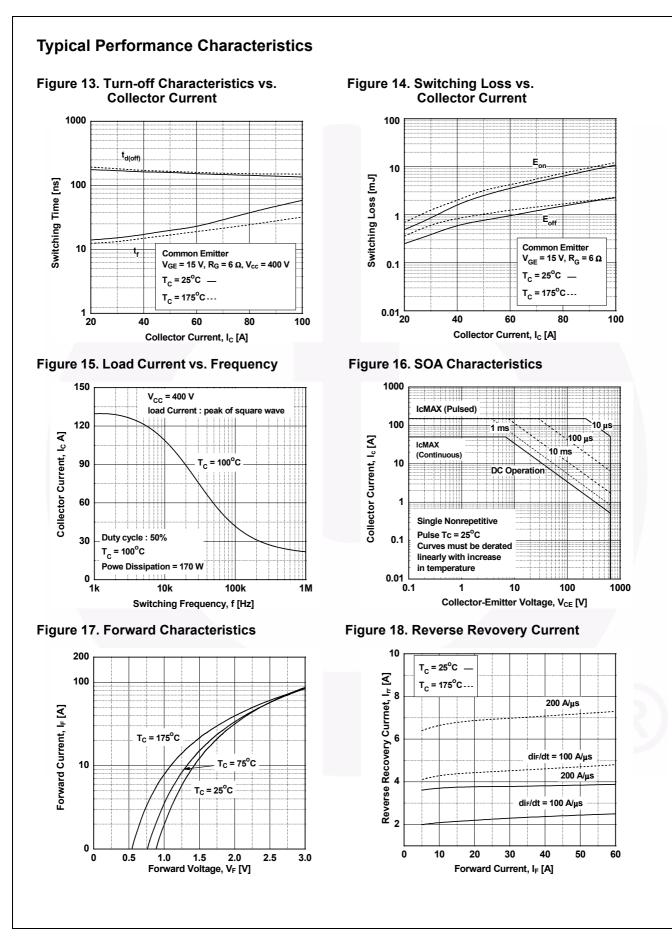
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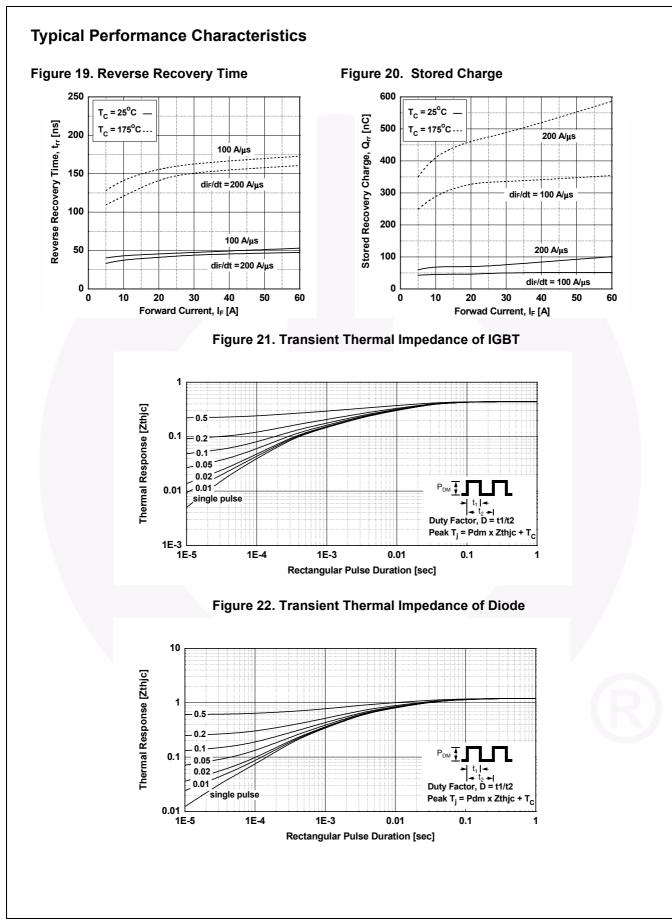


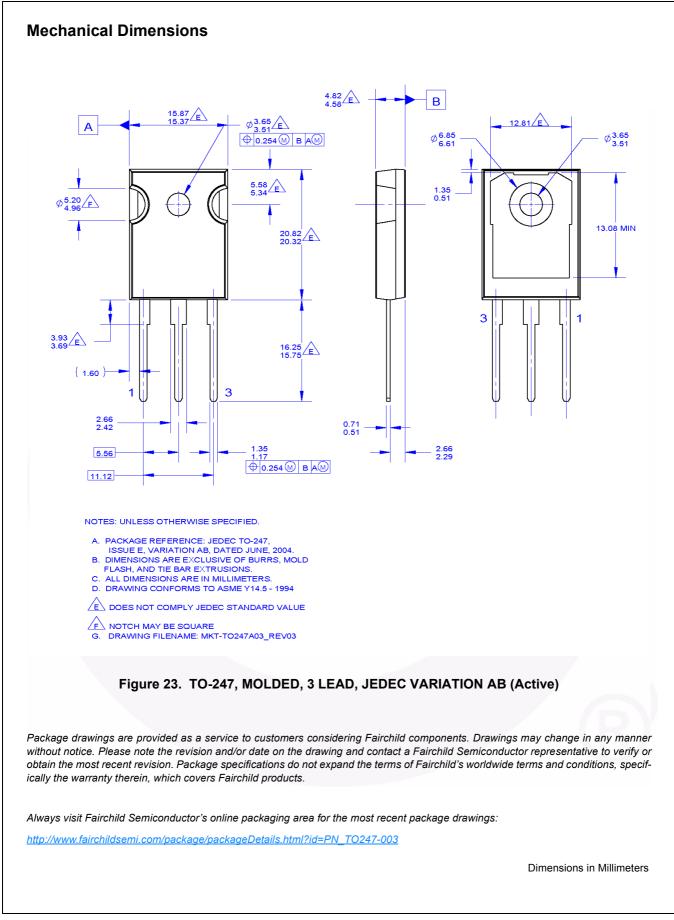
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FGH50T65UPD — 650 V, 50 A Field Stop Trench IGBT







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